## NSN 5961-00-845-1921

No Fiig: A110a0

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View Online at https://aerobasegroup.com/nsn/5961-00-845-1921 **Inclosure Material:** Glass and metal **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** 1.250 inches **Overall Diameter:** Between 0.108 inches and 0.140 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-14 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 0.10 microamperes forward current, average peak **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: